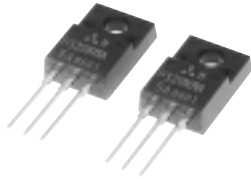


FS20KMA-5A

HIGH-SPEED SWITCHING USE

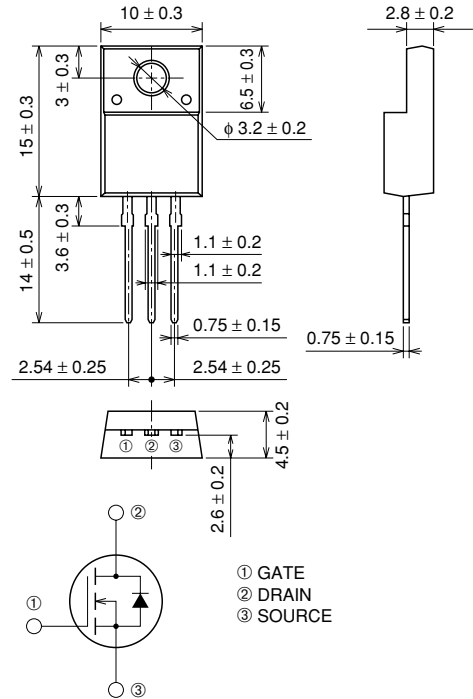
FS20KMA-5A



- 10V DRIVE
- V_{DSS} 250V
- r_{DS (ON)} (MAX) 0.20Ω
- I_D 20A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

CRT Display monitor, SMPS, etc.

MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	250	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±20	V
I _D	Drain current		20	A
I _{DM}	Drain current (Pulsed)		60	A
I _{DA}	Avalanche current (Pulsed)	L = 200μH	20	A
P _D	Maximum power dissipation		40	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
V _{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

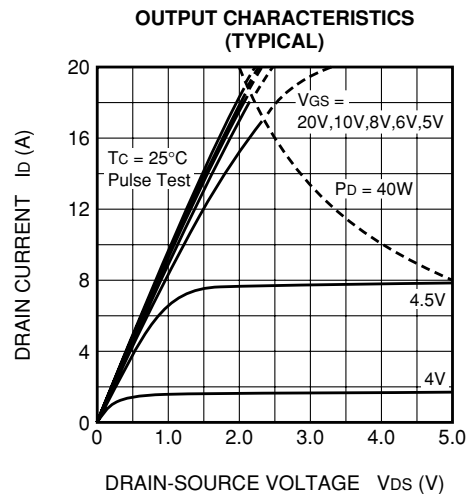
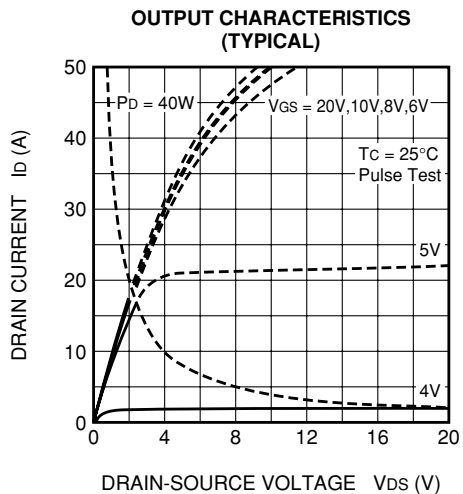
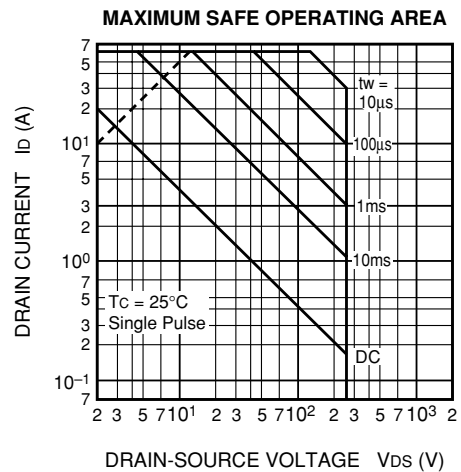
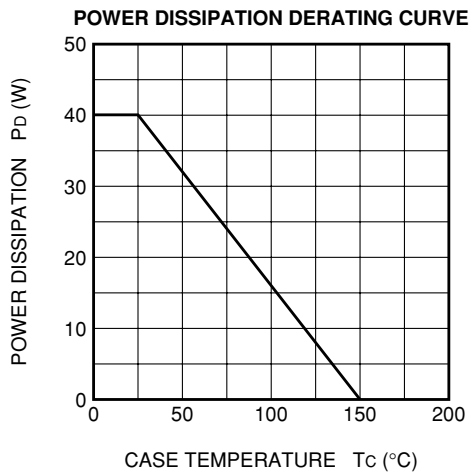
FS20KMA-5A

HIGH-SPEED SWITCHING USE

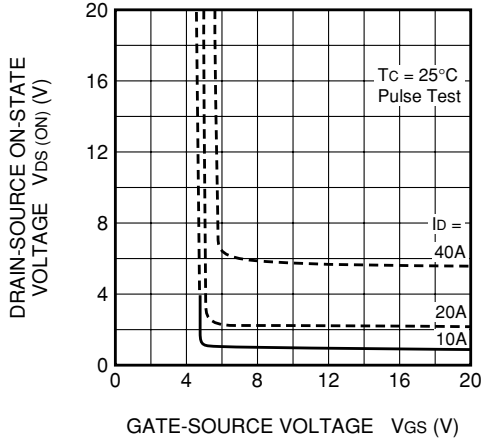
ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{(BR)DSS}	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	250	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±20V, V _{DS} = 0V	—	—	±0.1	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 250V, V _{GS} = 0V	—	—	1	mA
V _{GS(th)}	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	2.0	3.0	4.0	V
r _{DS(ON)}	Drain-source on-state resistance	I _D = 10A, V _{GS} = 10V	—	0.15	0.20	Ω
V _{DS(ON)}	Drain-source on-state voltage	I _D = 10A, V _{GS} = 10V	—	1.50	2.00	V
y _{fs}	Forward transfer admittance	I _D = 10A, V _{DS} = 10V	—	20.0	—	S
C _{iss}	Input capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	—	2250	—	pF
C _{oss}	Output capacitance		—	220	—	pF
C _{rss}	Reverse transfer capacitance		—	65	—	pF
t _{d(on)}	Turn-on delay time	V _{DD} = 150V, I _D = 10A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	35	—	ns
t _r	Rise time		—	70	—	ns
t _{d(off)}	Turn-off delay time		—	400	—	ns
t _f	Fall time		—	100	—	ns
V _{SD}	Source-drain voltage	I _S = 10A, V _{GS} = 0V	—	1.5	2.0	V
R _{th(ch-c)}	Thermal resistance	Channel to case	—	—	3.13	°C/W

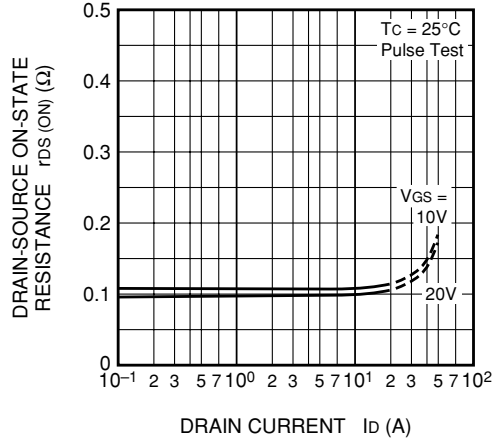
PERFORMANCE CURVES



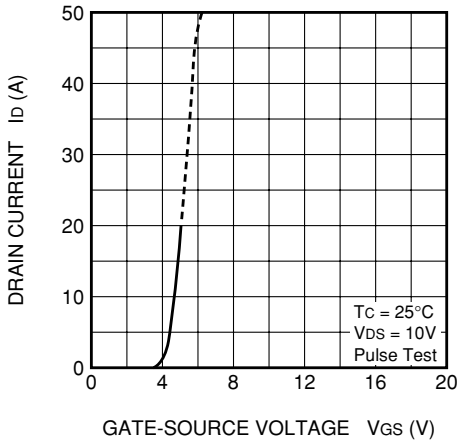
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



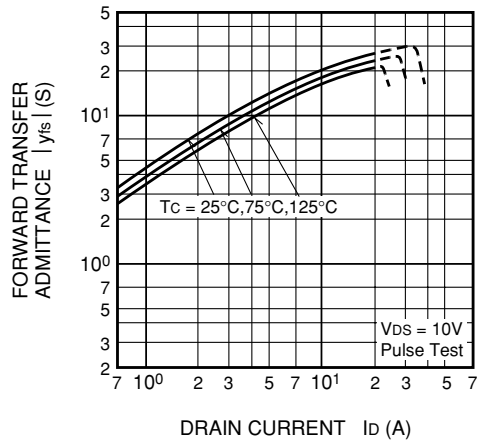
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



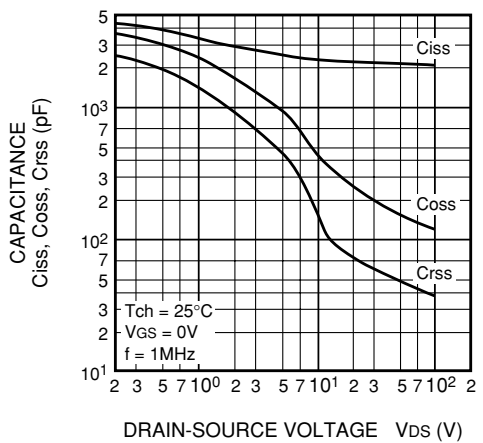
TRANSFER CHARACTERISTICS (TYPICAL)



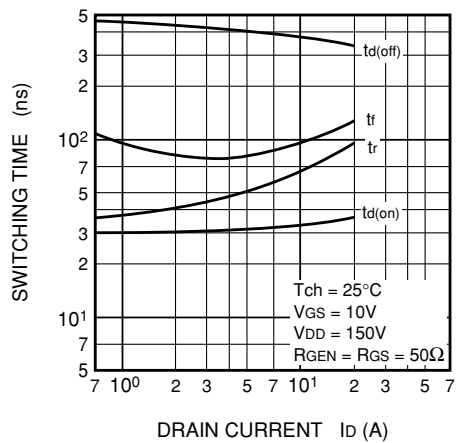
FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



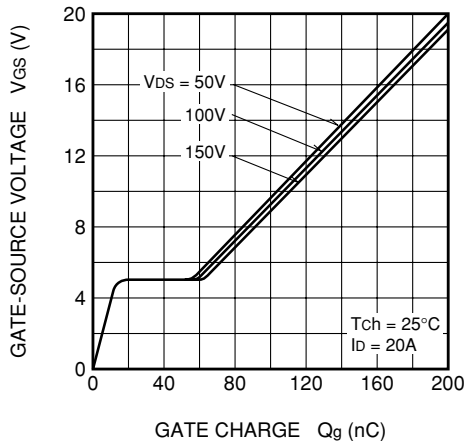
SWITCHING CHARACTERISTICS (TYPICAL)



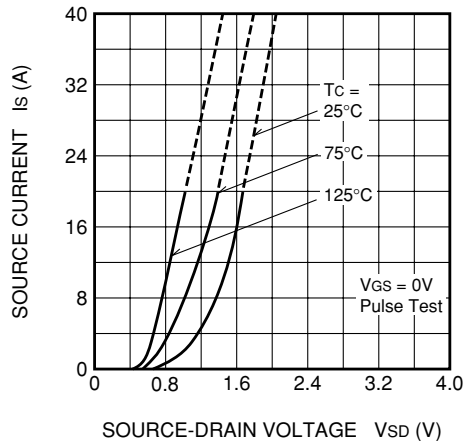
FS20KMA-5A

HIGH-SPEED SWITCHING USE

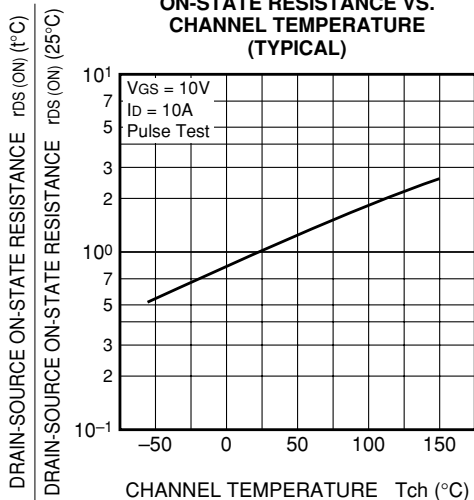
GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)



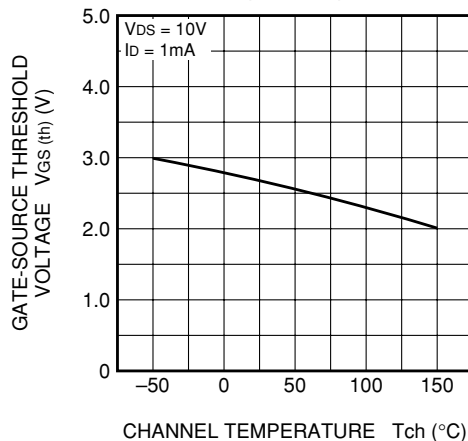
SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)



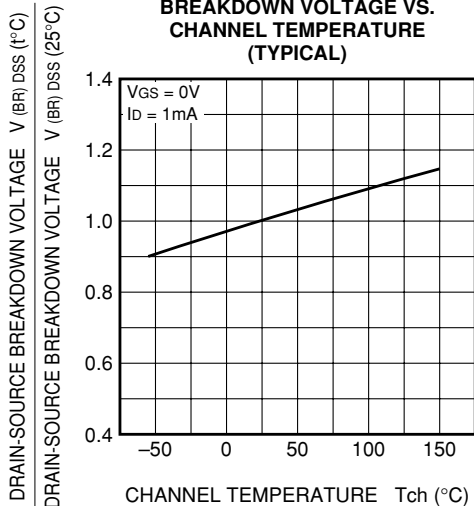
ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)



THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



BREAKDOWN VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS

